

PBHV9040T

500 V, 0.25 A PNP high-voltage low VCEsat transistor

Product data sheet

1. General description

PNP high-voltage low V_{CEsat} transistor in a SOT23 (TO-236AB) small Surface-Mounted Device (SMD) plastic package.

NPN complement: PBHV8540T

2. Features and benefits

- · High voltage
- Low collector-emitter saturation voltage V_{CEsat}
- High collector current capability I_C and I_{CM}
- High collector current gain (h_{FE}) at high I_C
- Small SMD plastic package

3. Applications

- · Electronic ballast for fluorescent lighting
- · LED driver for LED chain module
- LCD backlighting
- · High Intensity Discharge (HID) front lighting
- Automotive motor management
- Hook switch for wired telecom
- Switch Mode Power Supply (SMPS)

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CESM}	collector-emitter peak voltage	V _{BE} = 0 V	-	-	-500	V
V _{CEO}	collector-emitter voltage	open base	-	-	-400	V
I _C	collector current		-	-	-0.25	Α
h _{FE}	DC current gain	V_{CE} = -10 V; I_{C} = -50 mA; T_{amb} = 25 °C	100	200	-	



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	3	С
2	Е	emitter		j
3	С	collector		В — (
				 E
			1	sym013

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PBHV9040T	SOT23	plastic, surface-mounted package; 3 terminals; 1.9 mm pitch; 2.9 mm x 1.3 mm x 1 mm body	SOT23

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PBHV9040T	W5%

[1] % = placeholder for manufacturing site code

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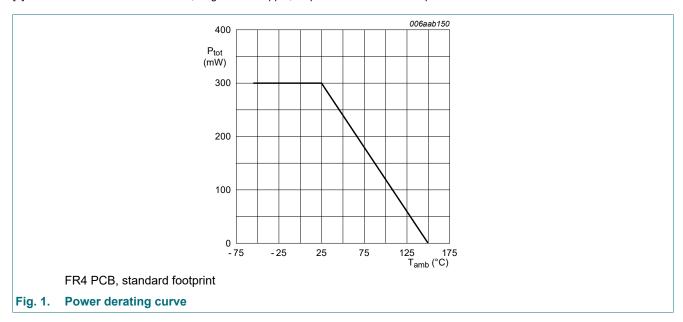
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter		-	-500	V
V _{CEO}	collector-emitter voltage	open base		-	-400	V
V _{CESM}	collector-emitter peak voltage	V _{BE} = 0 V		-	-500	V
V _{EBO}	emitter-base voltage	open collector		-	-6	V
I _C	collector current			-	-0.25	Α
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-0.5	Α
I _{BM}	peak base current			-	-200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	300	mW
T _j	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



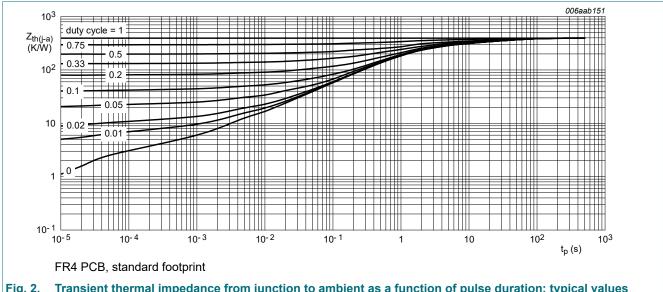
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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	417	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	70	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off	V _{CB} = -320 V; I _E = 0 A; T _{amb} = 25 °C	-	-	-100	nA
	current	V _{CB} = -320 V; I _E = 0 A; T _j = 150 °C	-	-	-10	μA
I _{EBO}	emitter-base cut-off current	V _{EB} = -4 V; I _C = 0 A; T _{amb} = 25 °C	-	-	-100	nA
I _{CES}	collector-emitter cut-off current	V _{CE} = -320 V; V _{BE} = 0 V; T _{amb} = 25 °C	-	-	-100	nA
h _{FE}	DC current gain	V _{CE} = -10 V; I _C = -50 mA; T _{amb} = 25 °C	100	200	-	
		V _{CE} = -10 V; I _C = -100 mA; T _{amb} = 25 °C	80	200	-	
		V_{CE} = -10 V; I_{C} = -250 mA; pulsed; $t_{p} \le$ 300 μs; $\delta \le$ 0.02; T_{amb} = 25 °C	10	25	-	
V _{CEsat}	collector-emitter saturation voltage	I_C = -100 mA; I_B = -20 mA; T_{amb} = 25 °C	-	-110	-200	mV
V _{BEsat}	base-emitter saturation voltage	I_C = -100 mA; I_B = -20 mA; pulsed; $t_p \le$ 300 μs; $\delta \le$ 0.02; T_{amb} = 25 °C	-	-1	-1.1	V
t _d	delay time	V _{CC} = -2 V; I _C = -0.15 A; I _{Bon} = -0.03 A;	-	9	-	ns
t _r	rise time	I _{Boff} = 0.03 A; T _{amb} = 25 °C	-	1810	-	ns
t _{on}	turn-on time		-	1819	-	ns
t _s	storage time		-	715	-	ns
t _f	fall time		-	1085	-	ns
t _{off}	turn-off time		-	1800	-	ns
f _T	transition frequency	V_{CE} = -10 V; I_{C} = -10 mA; f = 100 MHz; T_{amb} = 25 °C	-	55	-	MHz
C _c	collector capacitance	V _{CB} = -20 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	7	-	pF
C _e	emitter capacitance	V_{EB} = -0.5 V; I_{C} = 0 A; i_{c} = 0 A; f = 1 MHz; T_{amb} = 25 °C	-	150	-	pF

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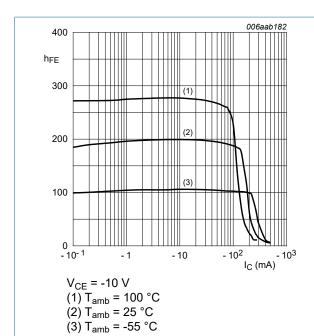


Fig. 3. DC current gain as a function of collector current; typical values

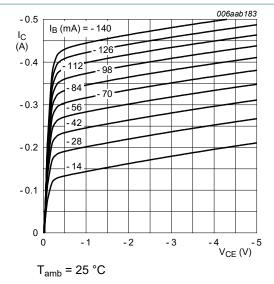


Fig. 4. Collector current as a function of collectoremitter voltage; typical values

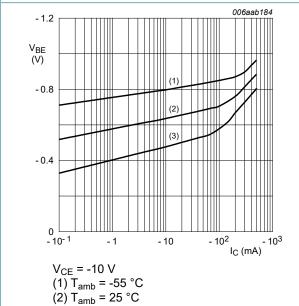
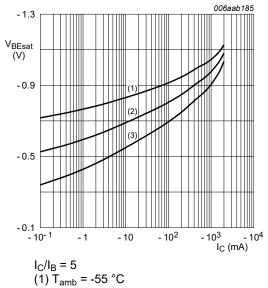


Fig. 5. Base-emitter voltage as a function of collector current; typical values

(3) $T_{amb} = 100 \, ^{\circ}C$



(2) $T_{amb} = 25 \, ^{\circ}C$ (3) $T_{amb} = 100 \, ^{\circ}C$

Fig. 6. Base-emitter saturation voltage as a function of collector current; typical values

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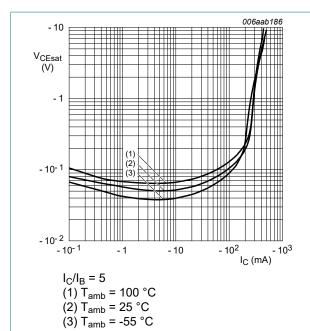


Fig. 7. Collector-emitter saturation voltage as a function of collector current; typical values

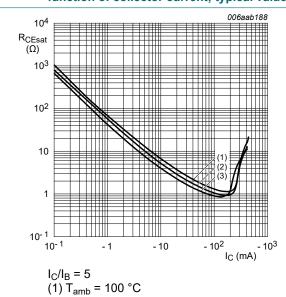


Fig. 9. Collector-emitter saturation resistance as a function of collector current; typical values

(2) $T_{amb} = 25 \, ^{\circ}C$

(3) T_{amb} = -55 °C

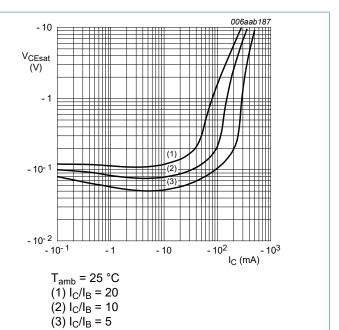


Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values

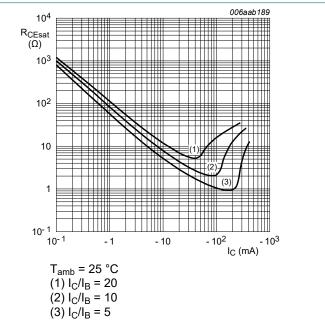
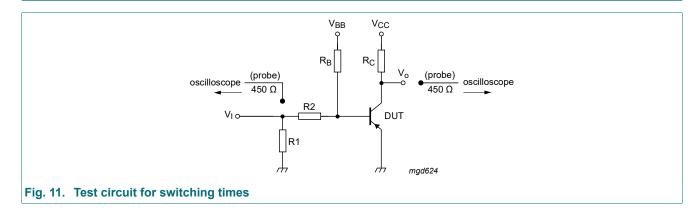


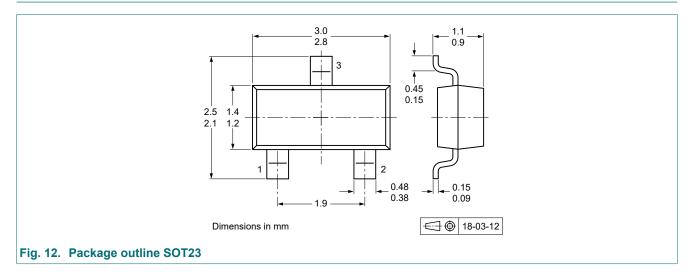
Fig. 10. Collector-emitter saturation resistance as a function of collector current; typical values

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11. Test information

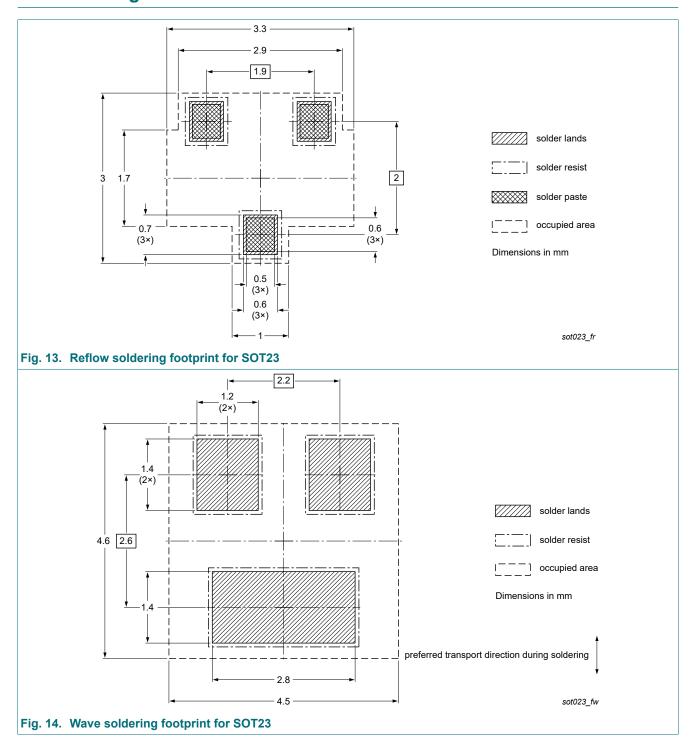


12. Package outline



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13. Soldering



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14. Revision history

Table 8. Revision history

Table of Iteriore				
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PBHV9040T v.3	20230101	Product data sheet	-	PBHV9040T_2
Modifications:	Nexperia. • Legal texts have	` ,	ompany name where app	propriate.
PBHV9040T_2	20090115	Product data sheet	-	PBHV9040T_1
PBHV9040T_1	20080212	Product data sheet	-	-

Product data sheet

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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